

Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use as many sheets as necessary)

Sheet 1 of 1

Complete if Known

Application Number 09/883795
Filing Date June 18, 2001
First Named Inventor Forbes, Leonard
Group Art Unit 2814
Examiner Name Doan, Theresa

Attorney Docket No: 303.355US4

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OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS

Examiner Initials *	Cite No	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ¹
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EXAMINER

Doan

DATE CONSIDERED

10/15/03

Substitute Disclosure Statement form (PTO 1449)
EXAMINER: Initial if reference is considered; whether or not relation is in conformity with MPEP 609. Draw line through citation if not in performance and not considered. Include copy of this form with next communication to applicant. Applicant's unique citation designation number (optional). Applicant is to place a check mark here if English language Translation is attached.